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Amorphization of Cu nanoparticles: Effects on surface plasmon resonance

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Crystalline copper nanoparticles (NPs) were formed in silica by multi-energy MeV ion implantations and then transformed to amorphous NPs by irradiation with 5 MeV Sn3+ ions. Optical absorption spectra of both the phases were evaluated in the ultra-violet to near-infrared regions. Compared with corresponding crystalline NPs of the same mean diameter, the amorphous NPs showed a low-energy shift of the surface plasmon resonance around 2.2 eV and less prominent absorption structure around 4 eV. These differences are explained by a strongly reduced electron mean-free-path in the amorphous NPs due to the loss of lattice periodicity. © 2011 American Institute of Physics. [doi:10.1063/1.3615307]

Surface plasmon resonance (SPR) of metal nanoparticles (NPs) has been subjected to extensive investigations aiming at applications to ultra-fast optical nonlinear devices,1 one-molecule detection by enhanced Raman spectroscopy,2 plasmonics,3 etc. While more than two thirds of the elements in the periodic table are metals, only NPs of very limited species, such as noble-metals and some exceptions, show a pronounced SPR simultaneously with chemical stability for practical applications. If amorphization preserves the pronounced SPR which is observed in the crystalline NPs of the same material, the number of the NP species showing a pronounced SPR increases in a single bound. Furthermore, the amorphization can be a new parameter controlling the SPR.

Because of the direction-insensitive nature of metal bondings, metals generally have structural flexibility against randomness introduced in the crystalline structures.4 This is in contrast with tetrahedrally bonded semiconductors, e.g., Si, Ge, etc, where the direction-sensitive bondings are weak against structural randomness. Consequently, semiconductors more easily suffer amorphization of their crystalline structures. Contrary, amorphous bulk metals which consist of only one element have never been successfully formed to date. While amorphous alloy metals in bulk form have been synthesized, the amorphous alloys consist of multi-elements, and in the most of the cases, they include a non-metallic element. In the form of thin films, past literature reported the formation of amorphous elemental metals of Fe (Ref. 5) by sonochemical processing. However, the amorphization was confirmed only by the disappearance of the x-ray diffraction (XRD) peaks and any information of the short-range order obtained by, e.g., the extended x-ray absorption fine structure (EXAFS) was not provided. It should be noted that XRD is not a powerful tool for determining whether a material is amorphous or nano-crystalline due to the extreme broadening of Bragg peaks with both decreasing crystal size and increasing amorphous fraction. Using vapor condensation at sub 20 K,6 an amorphous Co film of ∼5 nm thick was formed and the short-range order was evaluated at the same temperature by EXAFS. The EXAFS results were consistent with amorphization. However, the amorphous Co films were sensitive to temperature and re-crystallized much lower than room temperature (at around 120 K).

Ion irradiation has been recognized as an established technique to induce amorphization, mainly in semiconductors. If this technique also applies to metals, even in the form of thin film or nanostructures, various technologically relevant applications would be expected. Johannessen et al. have succeeded in the amorphization of Cu-NPs (Ref. 7) and Co-NPs (Ref. 8) embedded in thermally-oxidized SiO2 layers and have studied their structural properties using synchrotron based x-ray techniques such as x-ray absorption spectroscopy (XAS) and small angle x-ray scattering (SAXS). In this letter, optical absorption spectra of the amorphous Cu NPs in the ultra-violet (UV), visible (Vis), and near-infrared (NIR) regions. Compared with corresponding crystalline NPs of the same mean diameter, the amorphous NPs showed a low-energy shift of the surface plasmon resonance around 2.2 eV and less prominent absorption structure around 4 eV. These differences are explained by a strongly reduced electron mean-free-path in the amorphous NPs due to the loss of lattice periodicity. © 2011 American Institute of Physics. [doi:10.1063/1.3615307]

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1.45 Å and no peak around 2.2 Å, which correspond to Cu–O and Cu–Cu distances, respectively. This indicates that each Cu atom is surrounded by O atoms; i.e., the Cu atoms are isolated from each other by the silica matrix and no Cu NPs are formed. The corresponding absorption spectrum in the as-implanted state (curve (i) in Fig. 1(b)) shows very faint absorption in the Vis-NIR regions. A naked eye investigation did not observe any color in the sample as shown in Fig. 1(c-i). Since the SPR absorption around 2 eV is a consequence of aggregation of Cu atoms, the faint absorption in the Vis region is consistent with the EXAFS result.

After the implantations, the samples were annealed at 650 °C for 1 h in flowing forming gas (5%-H₂ + 95-N₂) to induce precipitation and growth of Cu NPs. The sample color changed from transparent to reddish brown (Fig. 1(c-ii)). As shown in Fig. 1(a), the 1.45 Å peak ascribed to isolated Cu atoms disappears and the 2.2 Å peak ascribed to the Cu–Cu nearest-neighbor (NN) shell has the strongest intensity. In addition, several peaks due to the next NN and higher order shells are observed at the longer distance side of the strongest peak. These features, including the peak intensity ratios between the higher order shells, are comparable to a bulk Cu standard, confirming the formation of crystalline Cu NPs. The corresponding optical absorption (curve (ii) in Fig. 1(b)) gradually increases with the photon energy with a broad SPR peak around 2.2 eV. Similar spectra have been reported extensively in past literature.1,10–12

After the annealing, the samples were irradiated with Sn³⁺ ions of 5 MeV up to a fluence of 1 × 10¹⁴ ions/cm² at LNT. The intensity of the NN Cu–Cu peak decreases as shown in Fig. 1(a). While the peaks of the higher order shells are very weak but faintly visible, the intensity ratios between the peaks are completely different from those of the crystalline NPs. These features are consistent with the past literature of the amorphization of thin Co films6 and of other alloy systems.13

After irradiation, the sample clearly changed color from reddish brown to dark brown (Fig. 1(c-iii)). The corresponding absorption spectrum is shown in Fig. 1(b). However, it should be noted that the observed spectrum might consist of not only the contribution of the amorphous Cu NPs but also those of others, i.e., radiation damage and dispersed Cu atoms.

Since the ion range of the 5 MeV Sn ions is much deeper than 2 µm, i.e., far beyond the NP layer (0.6–1.0 µm in depth), impurity effects of Sn ions in Cu NPs are negligible. For reference, a piece of virgin silica was irradiated by the Sn ions of the same energy and fluence. The absorption spectrum (curve (iii) in Fig. 1(b)) shows almost no absorption up to 4 eV but an absorption peak at around 5 eV. This is a typical absorption band of radiation-induced defects in the KU-1 type silica.14,15

In the spectrum of Sn-irradiated Cu NPs (curve (iii) in Fig. 1(b)), the same peak as described above was observed. To eliminate the contribution of such radiation-induced defects, curve (iv) was subtracted from curve (iii). After the subtraction, a smooth spectrum (not shown) was obtained in whole the UV region, which justifies this subtraction procedure.

As shown in Fig. 1(a), the Sn irradiation induced reappearance of the peak at 1.45 Å, from collision-induced dissolution of Cu NPs. The dissolution of metal NPs induced by irradiation of several MeV heavy ions is a relatively common phenomenon reported previously.16,17 From Fig. 1(a), it was estimated that 40 at. % of Cu existed as dispersed atoms and the remaining 60 at. % formed the NPs.7 In order to study the NP absorption profile only, curve (i) (weighted at 40%) was subtracted from curve (iii). The resulting absorption spectrum of amorphous Cu NPs is shown in Fig. 2(a) together with the spectrum of crystalline NPs before irradiation. For comparison, the spectra were normalized with the Cu content which forms NPs.

From SAXS measurements, the volume-weighted mean diameters were determined as 2.5 ± 0.1 nm and 2.7 ± 0.1 nm before and after the amorphization, respectively, indicating almost the same mean size (and size distribution).7 The electron mean-free-path (EMFP) l in crystalline Cu NPs of radius r is given

\[ l^{-1} = l_\infty^{-1} + A \frac{1}{r}, \]

where \( l_\infty \) and \ A \) denote the EMFP of bulk Cu of 42 nm and a constant of \ ~1 \), respectively.18 Assuming \ A \! = \! 1, the EMFP of crystalline Cu NPs of 2.5 nm in diameter was estimated as 1.2 nm. Much reduced EMFPs in NPs comparing with the
bulk are schematically shown in Fig. 2(b). Upon amorphization, the low-energy SPR peak (at around 2.2 eV) showed a small but certain shift and the absorption structure around 4 eV became less prominent (see Fig. 2(a)).

The EMFP dependence of the absorption spectra of Cu NPs in silica was calculated based on the classical size effect (an EMFP reduction) and is shown in Fig. 2(c). The complex dielectric function of Cu NPs \( \varepsilon(\omega) \) was given as a sum of the interband part \( \varepsilon_b(\omega) \) and the free electron part described by the Drude formula \( \varepsilon_{\text{Drude}}(\omega) \)

\[
\varepsilon(\omega) = \varepsilon_{\text{Drude}}(\omega) + \varepsilon_b(\omega) = 1 - \frac{\omega_p^2}{\omega^2 + i\omega/\tau} + \varepsilon_b(\omega). \tag{2}
\]

where \( \hbar \omega_p \) and \( \tau \) denote the bulk plasmon energy of 8.86 eV and the relaxation time. The relaxation time \( \tau \) changes with the EMFP \( I \) keeping the relation \( \tau = l/v_F \), where \( v_F \) denotes the Fermi velocity of Cu. The absorption spectra were calculated by the Maxwell-Garnett theory. See Ref. 9 for details.

The calculation well reproduced that with decreasing the EMFP, there were (I) a low-energy shift of the SPR and (II) less prominence of the 4 eV structure. Both the spectral features of the amorphous Cu NPs were explained by strongly reduced EMFP, in spite of the NP size remaining virtually unchanged upon amorphization.

These observations indicate that the EMFP of amorphous Cu NPs is clearly shorter than the crystalline value of 1.2 nm. On the other hand, Ioffe and Regel assumed that the EMFP of amorphous materials should be the same as or greater than the inter-atomic distance, which was determined as 0.22 nm from the EXAFS data shown in Fig. 1(a). Consequently, the range of the EMFP in the amorphous Cu NPs was estimated as

\[
0.22 \text{ nm} \leq \text{EMFP (amorphous Cu NPs)} \ll 1.2 \text{ nm}. \tag{3}
\]

In conclusion, we have presented optical absorption spectra of crystalline and amorphous Cu NPs embedded in silica. While the NP size remained virtually unchanged upon amorphization, it was found that the EMFP was significantly reduced. This can be explained by the increased number of scattering sites due to the loss of lattice periodicity.

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